NSN 5962-01-358-9081

Memory Microcircuit - Page 1 of 1



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End Application:
Ac/rmpe react basic
Features Provided:
Electrostatic sensitive
Criticality Code Justification:
Cbbl
Memory Device Type:
Prom
Special Features:
Esd; hci. Item altered from p/n 15-1326286-1
Nuclear Hardness Critical Feature:
Hardened
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0